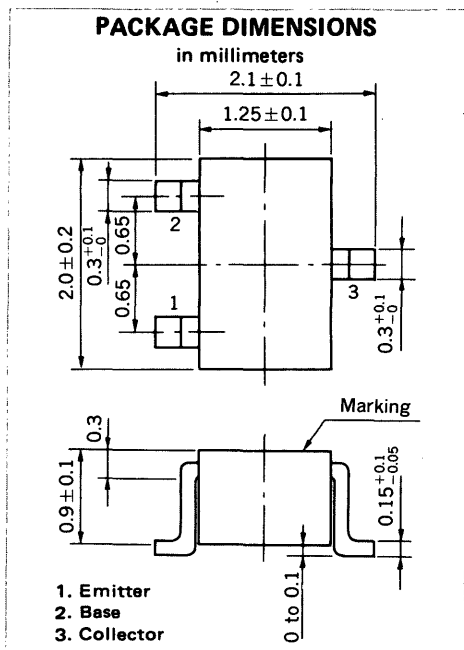


SILICON TRANSISTORS  
**2SC4181, 2SC4181A**

AUDIO FREQUENCY AMPLIFIER, SWITCHING  
NPN SILICON EPITAXIAL TRANSISTORS



**FEATURES**

- High DC Current Gain :  $h_{FE} = 1\ 000$  to  $3\ 200$
- Low  $V_{CE(sat)}$  :  $V_{CE(sat)} = 0.07\ V$  TYP.
- High  $V_{EBO}$  :  $V_{EBO} = 15\ V$  (2SC4181A)

**ABSOLUTE MAXIMUM RATINGS**

| Maximum Voltages and Current ( $T_a = 25\ ^\circ C$ ) |           | 2SC4181     | 2SC4181A |            |
|---|-----------|-------------|----------|------------|
| Collector to Base Voltage                             | $V_{CBO}$ | 60          |          | V          |
| Collector to Emitter Voltage                          | $V_{CEO}$ | 50          |          | V          |
| Emitter to Base Voltage                               | $V_{EBO}$ | 12          | 15       | V          |
| Collector Current (DC)                                | $I_C$     | 150         |          | mA         |
| Maximum Power Dissipation                             |           |             |          |            |
| Total Power Dissipation                               |           |             |          |            |
| at $25\ ^\circ C$ Ambient Temperature                 | $P_T$     | 150         |          | mW         |
| Maximum Temperatures                                  |           |             |          |            |
| Junction Temperature                                  | $T_j$     | 150         |          | $^\circ C$ |
| Storage Temperature Range                             | $T_{stg}$ | -55 to +150 |          | $^\circ C$ |

**ELECTRICAL CHARACTERISTICS ( $T_a = 25\ ^\circ C$ )**

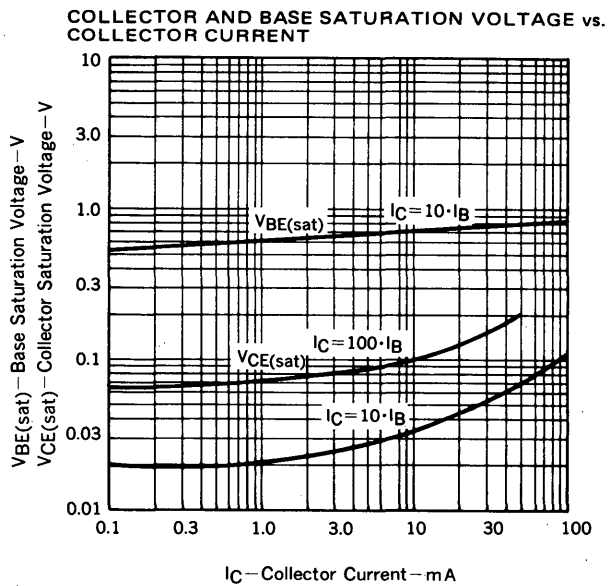
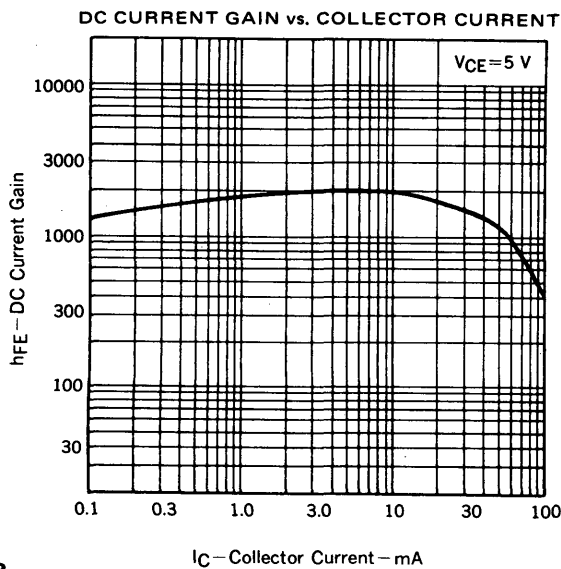
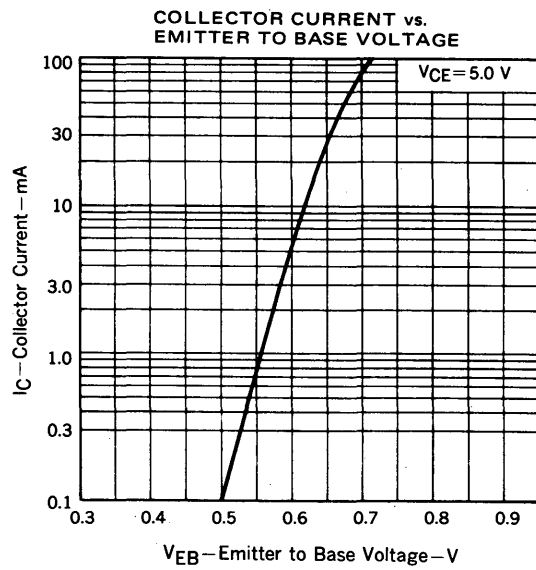
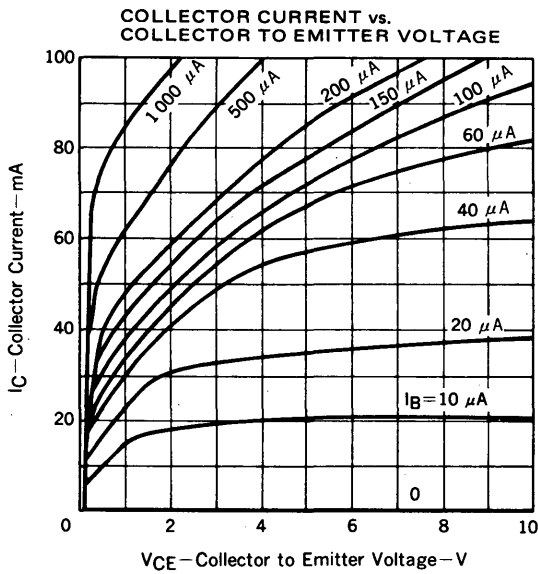
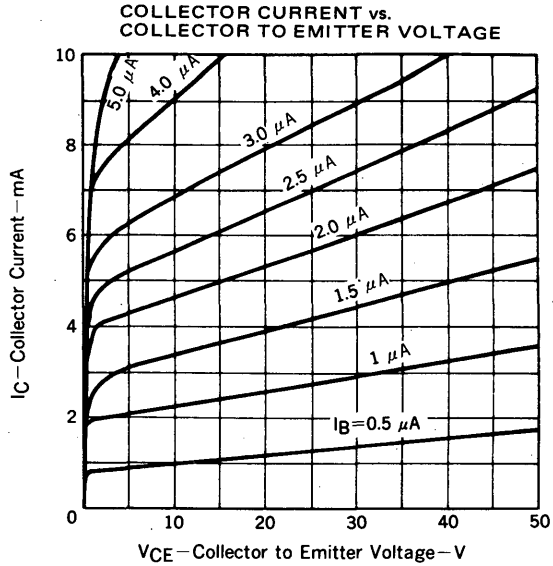
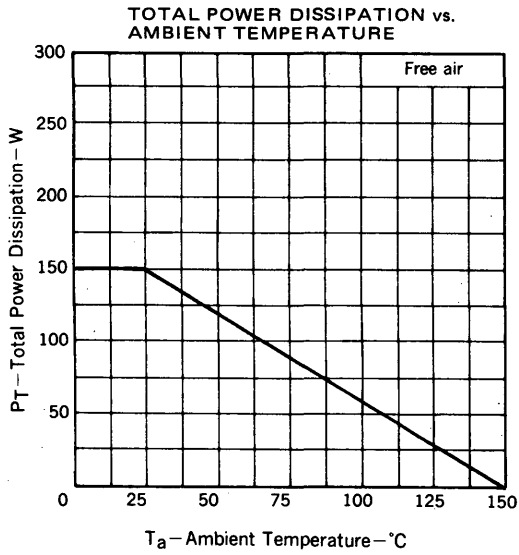
| CHARACTERISTIC               | SYMBOL          | MIN. | TYP. | MAX. | UNIT | TEST CONDITIONS                         |
|------------------------------|-----------------|------|------|------|------|---|
| Collector Cutoff Current     | $I_{CBO}$       |      |      | 100  | nA   | $V_{CB} = 50\ V, I_E = 0$               |
| Emitter Cutoff Current       | $I_{EBO}$       |      |      | 100  | nA   | $V_{EB} = 10\ V, I_C = 0$               |
| DC Current Gain              | $h_{FE1}^*$     | 1000 | 1800 | 3200 |      | $V_{CE} = 5.0\ V, I_C = 1.0\ mA$        |
| DC Current Gain              | $h_{FE2}^*$     | 200  | 350  |      |      | $V_{CE} = 5.0\ V, I_C = 100\ mA$        |
| Base to Emitter Voltage      | $V_{BE}^*$      |      | 0.56 |      | V    | $V_{CE} = 5.0\ V, I_C = 1.0\ mA$        |
| Collector Saturation Voltage | $V_{CE(sat)}^*$ |      | 0.07 | 0.3  | V    | $I_C = 50\ mA, I_B = 5.0\ mA$           |
| Base Saturation Voltage      | $V_{BE(sat)}^*$ |      | 0.8  | 1.2  | V    | $I_C = 50\ mA, I_B = 5.0\ mA$           |
| Gain Bandwidth Product       | $f_T$           |      | 250  |      | MHz  | $V_{CE} = 5.0\ V, I_E = -10\ mA$        |
| Output Capacitance           | $C_{ob}$        |      | 3.0  |      | pF   | $V_{CB} = 5\ V, I_E = 0, f = 1.0\ MHz$  |
| Turn-on Time                 | $t_{on}$        |      | 0.13 |      | ns   | $V_{CC} = 10\ V, V_{BE(off)} = -2.7\ V$ |
| Storage Time                 | $t_{stg}$       |      | 0.72 |      | ns   | $I_C = 50\ mA$                          |
| Turn-off Time                | $t_{off}$       |      | 1.22 |      | ns   | $I_{B1} = -I_{B2} = 1.0\ mA$            |

\*Pulsed:  $PW \leq 350\ \mu s, Duty\ Cycle \leq 2\ %$

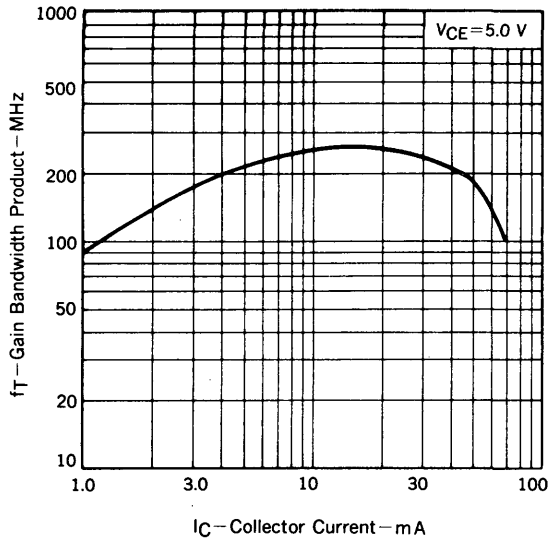
**$h_{FE}$  Classification**

| Marking   | 2SC4181      | L17          | L18 |
|-----------|--------------|--------------|-----|
|           | 2SC4181A     | L15          | L16 |
| $h_{FE1}$ | 1000 to 2000 | 1600 to 3200 |     |

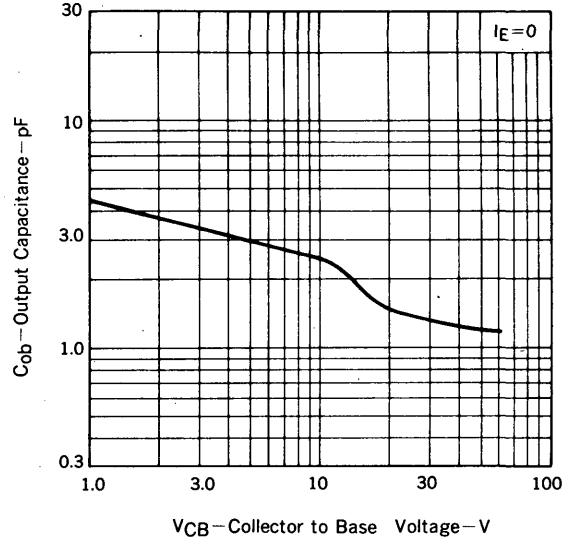
TYPICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )



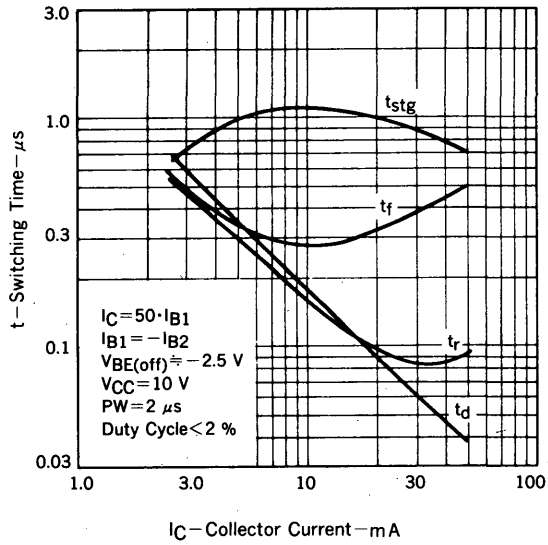
GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT



OUTPUT CAPACITANCE vs. COLLECTOR TO BASE VOLTAGE



SWITCHING TIME vs. COLLECTOR CURRENT



**[MEMO]**

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